BAS40-04LT1G

Dual Series Schottky Barrier Diode

These Schottky barrier diodes are designed for high speed switching applications, circuit protection, and voltage clamping. Extremely low forward voltage reduces conduction loss. Miniature surface mount package is excellent for hand held and portable applications where space is limited.

Features

- Extremely Fast Switching Speed
- Low Forward Voltage
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Reverse Voltage	V _R	40	V
Forward Power Dissipation @ T _A = 25°C Derate above 25°C	P _F	225 1.8	mW mW/°C
Operating Junction and Storage Temper- ature Range	T _{J,} T _{stg}	−55 to +150	°C
Forward Continuous Current	I _{FM}	120	mA
$\begin{array}{llllllllllllllllllllllllllllllllllll$	I _{FSM}	200 600	mA
Thermal Resistance Junction-to-Ambient	R _{θJA}	508 (Note 1) 311 (Note 2)	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-4 @ minimum pad.

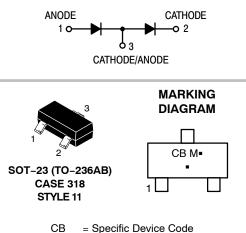
2. FR-4 @ 1.0 x 1.0 in pad.

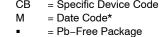


ON Semiconductor®

http://onsemi.com

40 VOLTS SCHOTTKY BARRIER DIODES





(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
BAS40-04LT1G	SOT-23 (Pb-Free)	3000/ Tape & Reel

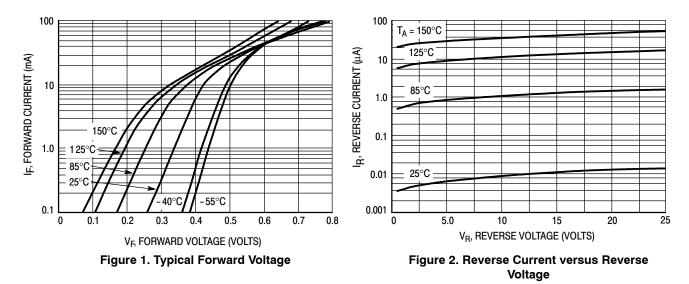
+ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

BAS40-04LT1G

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteri	Symbol	Min	Max	Unit	
Reverse Breakdown Voltage	(I _R = 10 μA)	V _{(BR)R}	40	-	V
Total Capacitance	(V _R = 1.0 V, f = 1.0 MHz)	CT	-	5.0	pF
Reverse Leakage (V _R = 25 V)		I _R	-	1.0	μΑ
Forward Voltage	(I _F = 1.0 mA)	V _F	-	380	mV
Forward Voltage	(I _F = 10 mA)	V _F	-	500	mV
Forward Voltage	(I _F = 40 mA)	V _F	-	1.0	V

BAS40-04LT1G



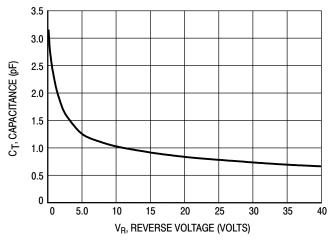
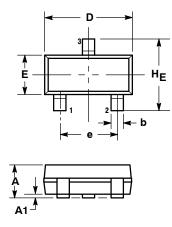
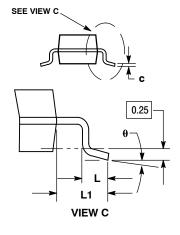


Figure 3. Typical Capacitance

PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AN**





- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH
- 3. THICKNESS, MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- 318-01 THRU -07 AND -09 OBSOLETE, NEW STANDARD 4. 318-08.

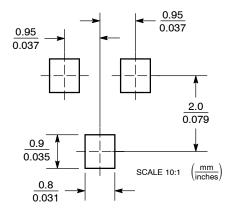
	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
С	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104

STYLE 11: PIN 1. ANODE

2. CATHODE

CATHODE-ANODE 3

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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